

## RESEARCH ARTICLE

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12, 8055Subgrid cage confinement engineering enabled  
ultra-efficient near-infrared Cr<sup>3+</sup>–Ln<sup>3+</sup> co-doped  
phosphorsSimeng Cao,<sup>a</sup> Shaoan Zhang,<sup>a</sup> Ximei An,<sup>a</sup> Lei Yang,<sup>a</sup> Mengting Gao,<sup>a</sup>  
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Precise control of energy migration between Cr<sup>3+</sup> sensitizers and Ln<sup>3+</sup> activators at the topochemical subgrid level remains a fundamental challenge. Herein, a novel subgrid cage confinement engineering strategy was proposed, achieving ultra-efficient near-infrared (NIR) Cr<sup>3+</sup>–Ln<sup>3+</sup> (Ln = Yb, Nd, Er) co-doped phosphors. The bilayer cage architecture of GdAl<sub>1.5</sub>Ga<sub>1.5</sub>(BO<sub>3</sub>)<sub>4</sub> precisely confines Ln<sup>3+</sup> at the central Gd<sup>3+</sup> sites, while providing octahedral lattice positions for Cr<sup>3+</sup> substitution within the Al/GaO<sub>6</sub> framework. This unique confinement constrains Cr<sup>3+</sup>–Ln<sup>3+</sup> separation to the optimal 3.67 Å while increasing the Ln<sup>3+</sup>–Ln<sup>3+</sup> distance to 5.92 Å, enabling highly efficient Cr<sup>3+</sup>–Ln<sup>3+</sup> energy transfer ( $\eta_{\text{ETE}}$ : 61% for Yb<sup>3+</sup>, 82% for Nd<sup>3+</sup>, 46% for Er<sup>3+</sup>) and suppressing energy losses between neighbouring Ln<sup>3+</sup> ions. Consequently, the Cr<sup>3+</sup>–Yb<sup>3+</sup> co-doped system achieved a high photoluminescence quantum yield of 86% and retained 94% of its intensity even at 423 K, demonstrating exceptional thermal stability. The fabricated NIR phosphor-converted light-emitting diodes delivered a NIR output power of 127 mW with a photoelectric efficiency of 13% under a 300 mA operating current. These capabilities enabled high-contrast biological imaging applications, such as vein visualization and non-destructive testing, as validated by prototype demonstrations.

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## 1. Introduction

In near-infrared (NIR) luminescent materials, Cr<sup>3+</sup>–Ln<sup>3+</sup> co-doped systems exhibit significant advantages through precise interionic energy transfer and local structural modulation strategies. These systems can extend their emission spectra to an ultra-broad band of 650–1600 nm, fully covering the three characteristic optical transparency windows of biological tissues (Window I: 700–950 nm; Window II: 1000–1350 nm; Window III: 1500–1800 nm).<sup>1,2</sup> Simultaneously, the broadband absorption of Cr<sup>3+</sup> (300–650 nm) efficiently sensitizes rare-earth ions, significantly enhancing the excitation efficiency of Ln<sup>3+</sup> (e.g., Yb<sup>3+</sup>, Nd<sup>3+</sup>, and Er<sup>3+</sup>), thereby overcoming the inherent limitation of small absorption cross-sections in conventional rare-earth materials.<sup>3–5</sup> However, the photoluminescence quantum yield (PLQY) of these systems is strictly constrained by the Cr<sup>3+</sup> → Ln<sup>3+</sup> energy transfer efficiency ( $\eta_{\text{ETE}}$ ), which is intrinsically linked to ionic lattice occupancy, doping concentration, chemical states,

and local crystal field environments.<sup>6,7</sup> Conventional strategies involve screening host lattice sites (e.g., ensuring Cr<sup>3+</sup> occupies octahedral sites while Ln<sup>3+</sup> occupies high-coordination dodecahedral sites) and modulating unit cell parameters in solid solutions (e.g., (Y,Lu)<sub>3</sub>(Al,Ga)<sub>5</sub>O<sub>12</sub>) to optimize the Cr<sup>3+</sup>–Ln<sup>3+</sup> separation to the ideal energy transfer distance of 3–6 Å.<sup>8,9</sup> Although these approaches can enhance luminescence efficiency, achieving precise control over energy migration at the topochemical subgrid level remains a fundamental challenge.<sup>10,11</sup>

Addressing this challenge, we proposed an innovative subgrid cage structure design strategy: drawing inspiration from confinement engineering concepts in nanocages, molecular cages, and metal–organic frameworks, we constructed discrete structural units with permanent cavities within an inorganic lattice.<sup>12</sup> These subgrid cages create a unique energy-modulation environment—leveraging spatial confinement effects to precisely control ion separation and coordination fields, while utilizing their large-volume independent unit characteristics to optimize energy migration pathways.<sup>13</sup> In practical implementation, we designed subgrid cages with bilayer/multilevel structures within an inorganic host (Fig. 1), successfully synthesizing highly efficient NIR Cr<sup>3+</sup>–Ln<sup>3+</sup> co-doped luminescent materials. Within the GdAl<sub>1.5</sub>Ga<sub>1.5</sub>(BO<sub>3</sub>)<sub>4</sub> host, Gd<sup>3+</sup> ions reside within an inner cage formed by BO<sub>3</sub> tri-

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**Fig. 1** (a) Three-dimensional crystallographic structure of  $\text{GdAl}_{1.5}\text{Ga}(\text{BO}_3)_4$ . (b) The double cage structure of the central  $\text{Gd}^{3+}$  ions consists of the  $\text{Al}/\text{GaO}_6$  polyhedron along with the  $[\text{BO}_3]$  polyhedron. (c) The local crystal structure of the central  $\text{Gd}^{3+}$  ions.

angular units, while  $\text{AlO}_6/\text{GaO}_6$  octahedra constitute an outer cage.<sup>14</sup> When  $\text{Cr}^{3+}\text{-Ln}^{3+}$  ion pairs occupy Gd and Al/Ga sites, respectively, the separation between adjacent  $\text{Gd}^{3+}$  ions exceeds 5 Å, whereas the  $\text{Cr}^{3+}\text{-Ln}^{3+}$  pair distance is only 3.673 Å.<sup>15</sup> This bilayer cage structure not only suppresses energy migration between  $\text{Ln}^{3+}$  ions but also promotes highly efficient energy transfer between the sensitizer ( $\text{Cr}^{3+}$ ) and the luminescent center ( $\text{Ln}^{3+}$ ) within the cage.

Based on this strategy,  $\text{GdAl}_{1.5}\text{Ga}_{1.5}(\text{BO}_3)_4:\text{Cr}^{3+},\text{Ln}^{3+}$  ( $\text{Ln} = \text{Yb}, \text{Nd}, \text{Er}$ ) is established as a novel class of high-performance NIR phosphors. A key breakthrough is the achievement of highly efficient  $\text{Cr}^{3+} \rightarrow \text{Ln}^{3+}$  energy transfer ( $\eta_{\text{ETE}}$ : 61% for  $\text{Yb}^{3+}$ ; 82% for  $\text{Nd}^{3+}$ ; 46% for  $\text{Er}^{3+}$ ), with the  $\text{Cr}^{3+}\text{-Yb}^{3+}$  co-doped system exhibiting a PLQY of 86% while retaining 94% photoluminescence (PL)

intensity at 423 K. The fabricated NIR phosphor-converted light-emitting diodes (pc-LEDs) demonstrate performance metrics meeting industrial application standards: the peak output power reaches 127 mW with a photoelectric conversion efficiency (PCE) of 13% under a 300 mA driving current, surpassing the comprehensive performance of existing  $\text{Cr}^{3+}$ -doped phosphor systems.

## 2. Experimental section

### 2.1. Sample synthesis

A series of compounds, denoted as  $\text{GAGBO}:\text{xCr}^{3+}$ ,  $\text{GAGBO}:\text{xCr}^{3+},\text{yYb}^{3+}$ ,  $\text{GAGBO}:\text{xCr}^{3+},\text{yNd}^{3+}$ , and  $\text{GAGBO}:\text{xCr}^{3+},\text{yEr}^{3+}$  (where GAGBO represents  $\text{GdAl}_{1.5}\text{Ga}(\text{BO}_3)_4$ ), were synthesized

via a standard high-temperature solid-state reaction method. The starting materials comprised high-purity oxides: gadolinium oxide ( $\text{Gd}_2\text{O}_3$ , 99.99%), aluminum oxide ( $\text{Al}_2\text{O}_3$ , 99.99%), gallium oxide ( $\text{Ga}_2\text{O}_3$ , 99.99%), boron trioxide ( $\text{B}_2\text{O}_3$ , 99.95%), chromium(III) oxide ( $\text{Cr}_2\text{O}_3$ , 99.95%), ytterbium oxide ( $\text{Yb}_2\text{O}_3$ , 99.99%), neodymium oxide ( $\text{Nd}_2\text{O}_3$ , 99.99%), and erbium oxide ( $\text{Er}_2\text{O}_3$ , 99.99%).

Stoichiometric amounts of the precursors were accurately weighed, vigorously ground in an agate mortar to ensure homogeneous mixing, and then transferred into an alumina crucible. The mixture underwent a two-stage thermal treatment in a muffle furnace: first, preheating at 500 °C for 2 hours to eliminate volatile impurities and enhance precursor interactions, and subsequently, calcination at 1100 °C for 6 hours to achieve phase formation and crystallization. Following sintering, the samples were allowed to cool naturally to ambient temperature within the furnace before further characterization.

## 2.2. Characterization

The phase composition of the powder samples was characterized by powder X-ray diffraction using a Bruker D8 Advance diffractometer with  $\text{Cu K}\alpha_1$  radiation ( $\lambda = 1.5406 \text{ \AA}$ ) at 36 kV and 20 mA. Diffraction patterns were recorded across the  $2\theta$  range from  $10^\circ$  to  $80^\circ$ . X-ray photoelectron spectroscopy was conducted on a Thermo Scientific K-Alpha spectrometer (USA) to analyze elemental composition and chemical states. Optical properties were systematically investigated using a UV-Vis-NIR spectrophotometer (PerkinElmer Lambda 750) and an Edinburgh FLS1000 photoluminescence system equipped with a TAP-02 temperature-controlled cryostat (operating range: 77–300 K). Microstructural analysis was performed by scanning electron microscopy on a ZEISS Sigma 360 instrument (Germany) at an accelerating voltage of 30 kV.

The optoelectronic performance of the fabricated NIR pc-LED devices, including PCE and output power, was characterized using a HAAS 2000 photometric and electrical testing system.

## 2.3. NIR pc-LED device fabrication

The synthesized NIR phosphors—GAGBO: $\text{Cr}^{3+}$ , GAGBO: $\text{Cr}^{3+}$ ,  $\text{Yb}^{3+}$ , and GAGBO: $\text{Cr}^{3+}$ ,  $\text{Nd}^{3+}$ —were thoroughly mixed with silicone resins A and B (mass ratio A : B = 1 : 10) at a phosphor-to-silicone weight ratio of 1 : 2. The homogeneous mixture was dispensed onto 450 nm LED chips (nominal power: 10 W). The coated chips were then cured in a constant-temperature oven at 150 °C for 4 hours to complete the encapsulation.

# 3. Results and discussion

## 3.1. Analysis of the crystal structure and morphology

Fig. 2a presents the X-ray diffraction (XRD) patterns of  $\text{GdAl}_{1.5}\text{Ga}_{1.5-x}(\text{BO}_3)_4 \cdot x\text{Cr}^{3+}$  phosphors at varying doping concentrations ( $x$ ). All diffraction patterns exhibit excellent agreement with the reference PDF# 51-0584 (GAGBO), confirming

the phase purity of the synthesized NIR phosphors. Fig. S1 shows the XRD patterns for GAGBO:0.15 $\text{Cr}^{3+}$ ,  $\text{yYb}^{3+}$  ( $y = 0.05, 0.12$ ), GAGBO:0.15 $\text{Cr}^{3+}$ ,  $\text{yNd}^{3+}$  ( $y = 0.12, 0.15$ ) and GAGBO:0.15 $\text{Cr}^{3+}$ ,  $\text{yEr}^{3+}$  ( $y = 0.05, 0.12$ ). All XRD patterns in Fig. S1 match well with PDF# 51-0584, indicating that  $\text{Cr}^{3+}$  and  $\text{Ln}^{3+}$  co-doping did not destroy the crystal structure of the  $\text{GdAl}_{1.5}\text{Ga}_{1.5}(\text{BO}_3)_4$  host. To determine the valence state of Cr, X-ray photoelectron spectroscopy (XPS) analysis was performed. Fig. 2b shows the full survey scan, where the binding energies at 141.7 eV, 19.7 eV, 193.7 eV, 74.7 eV, 530.7 eV and 594.7 eV correspond to Gd-4d, Ga-3d, B-1s, Al-2p, O-1s, and Cr-2p, respectively.

Fig. 2c, d and Fig. S2 present detailed XPS spectra for Gd-4d, Ga-3d, B-1s, Al-2p, O-1s, and Cr-2p from the GAGBO:0.08 $\text{Cr}^{3+}$  phosphor. Notably, the Cr-2p spectrum reveals only the presence of  $\text{Cr}^{3+}$ , with no detectable signals corresponding to  $\text{Cr}^{4+}$  or  $\text{Cr}^{6+}$ , confirming that chromium exists exclusively in the trivalent state. Fig. 2e shows scanning electron micrographs (SEM) and energy-dispersive spectroscopy (EDS) analysis of the GAGBO:0.08 $\text{Cr}^{3+}$  phosphor. The polyhedral particles have a diameter of approximately 2–3  $\mu\text{m}$ . Complementary elemental mapping by EDS performed on randomly selected particles further confirms the homogeneous spatial distribution of all constituent elements: Gd, Al, Ga, B, O, and Cr.

## 3.2. Photoluminescence properties

Fig. 3a presents the diffuse reflectance spectra of the undoped GAGBO, GAGBO:0.08 $\text{Cr}^{3+}$ , GAGBO:0.15 $\text{Cr}^{3+}$ , 0.12 $\text{Yb}^{3+}$  and GAGBO:0.15 $\text{Cr}^{3+}$ , 0.08 $\text{Nd}^{3+}$ . Notably,  $\text{Cr}^{3+}$  doping introduces two distinct absorption bands within the 350–800 nm range. These bands are assigned to the characteristic spin-allowed transitions of  $\text{Cr}^{3+}$ : the higher-energy band to the  ${}^4\text{A}_2 \rightarrow {}^4\text{T}_1({}^4\text{F})$  transition and the lower-energy band to the  ${}^4\text{A}_2 \rightarrow {}^4\text{T}_2({}^4\text{F})$  transition.<sup>16,17</sup> Notably, these characteristic absorption features persist in the spectra of  $\text{Yb}^{3+}$  and  $\text{Nd}^{3+}$  co-doped samples (Fig. S3). Strong absorption was observed in the 250–350 nm range, referred to as the Tauc region, which arises from valence-to-conduction band transitions.<sup>18,19</sup> The optical bandgap ( $E_{\text{opt}}$ ) was determined using Tauc's relation:<sup>20,21</sup>

$$(\alpha h\nu)^2 = A(h\nu - E_{\text{opt}}) \quad (1)$$

Here,  $\alpha$  is the absorption coefficient, approximated from the reflectance ( $R_\infty$ ) data using the Kubelka–Munk relation:<sup>22</sup>

$$\alpha \propto \frac{(1 - R_\infty)^2}{2R_\infty} \quad (2)$$

Fig. S4 shows plots of  $(\alpha h\nu)^2$  versus photon energy ( $h\nu$ ). Linear extrapolation of the absorption edge in this Tauc plot yields an estimated indirect optical bandgap of 4.10 eV. Fig. 3b shows the representative photoluminescence excitation (PLE) and PL spectra of the  $\text{Cr}^{3+}$ -doped phosphor. The PLE spectrum exhibits two distinct excitation bands: one in the 350–500 nm region and another in the 500–700 nm region. These two bands are attributed to the spin-allowed  ${}^4\text{A}_2 \rightarrow {}^4\text{T}_1({}^4\text{F})$  and



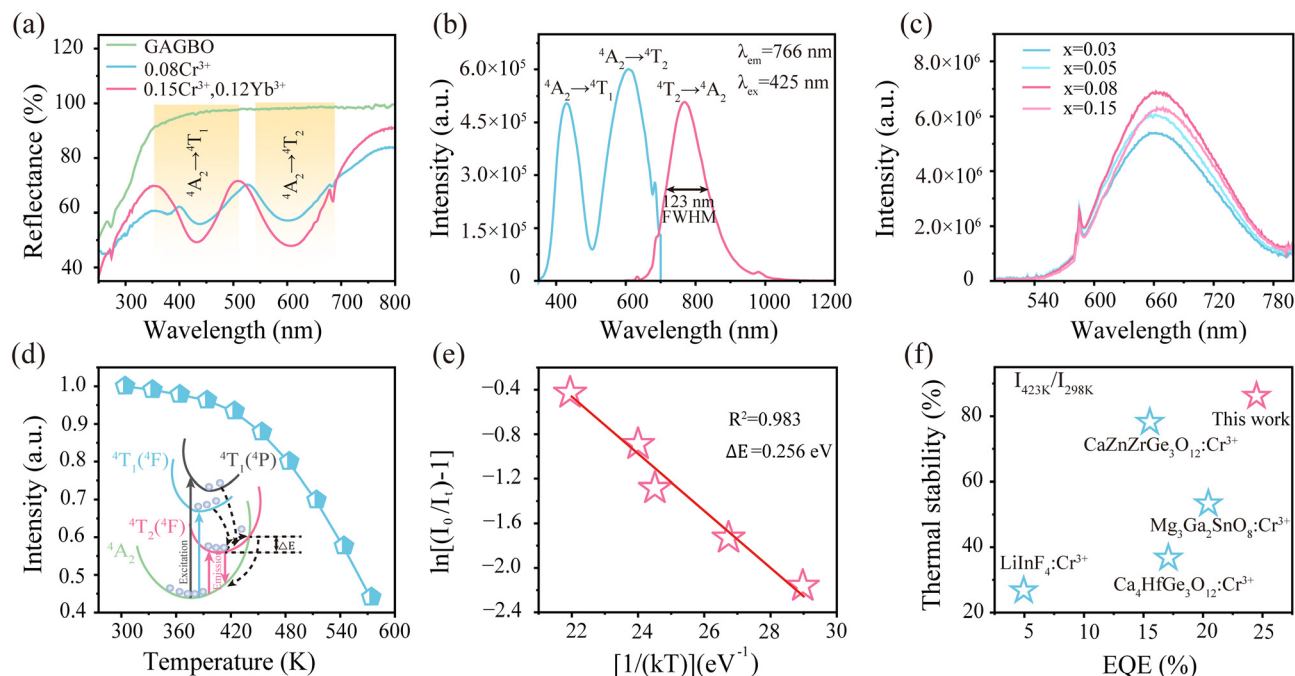
**Fig. 2** (a) The XRD patterns of the GAGBO: $x\text{Cr}^{3+}$  ( $x = 0.03\text{--}0.15$ ) phosphors. (b) The XPS spectra of GAGBO: $0.08\text{Cr}^{3+}$ . (c and d) The detailed regions for Gd-4d, Ga-3d, B-1s, Al-2p and Cr-2p. (e) SEM images and EDS elemental mapping graphs of GAGBO: $0.08\text{Cr}^{3+}$ .

${}^4\text{A}_2 \rightarrow {}^4\text{T}_2({}^4\text{F})$  transitions of  $\text{Cr}^{3+}$ , respectively.<sup>23</sup> Upon excitation at 425 nm, a broad NIR emission band centered at 766 nm is observed. This emission originates from the radiative  ${}^4\text{T}_2({}^4\text{F}) \rightarrow {}^4\text{A}_2$  transition of  $\text{Cr}^{3+}$ . The agreement between these excitation bands and the absorption features in the diffuse reflectance spectra (Fig. 3a) confirms  $\text{Cr}^{3+}$  as an effective NIR luminescent center in this GAGBO host.

To investigate the concentration dependence of the  $\text{Cr}^{3+}$  NIR luminescence, a series of  $\text{Cr}^{3+}$ -doped phosphors with varying  $\text{Cr}^{3+}$  concentrations were synthesized. Fig. 3c presents their concentration-dependent PL spectra recorded under identical excitation conditions. Irrespective of the doping level, all samples exhibit a single, broad emission band peaking at 766 nm. Notably, GAGBO: $0.08\text{Cr}^{3+}$  shows extensive NIR emission with a full width at half maximum of 123 nm (Fig. 3b), which is in agreement with the emission of commercial blue LEDs.<sup>24</sup> The PL intensity increases with rising  $\text{Cr}^{3+}$  concentration, reaching a maximum at the optimal concentration of  $x = 0.08$ . Further increases in  $x$  beyond this doping concentration lead to a gradual decline due to concentration quench-

ing of  $\text{Cr}^{3+}$ . This quenching is attributed to enhanced non-radiative energy transfer between neighboring  $\text{Cr}^{3+}$  ions at higher doping concentrations.<sup>25,26</sup>

Thermal stability is a critical performance parameter for  $\text{Cr}^{3+}$ -doped phosphors in solid-state lighting, particularly given that operational temperatures of LED chips can reach 423 K (150 °C)—a regime where thermal quenching typically degrades emission.<sup>27</sup> Fig. 3d presents the temperature-dependent PL intensity of the optimized GAGBO: $0.08\text{Cr}^{3+}$  phosphor. The integrated emission intensity gradually decreases with increasing temperature due to thermal quenching. Significantly, at 423 K (150 °C), the PL intensity retains 93% of its room-temperature value, demonstrating the exceptional thermal stability of GAGBO: $0.08\text{Cr}^{3+}$  phosphors. The inset of Fig. 3d illustrates the underlying thermal quenching mechanism. Following excitation by blue light, electrons are promoted from the  ${}^4\text{A}_2$  ground state to higher-energy configurations:  ${}^4\text{T}_1({}^4\text{P})$ ,  ${}^4\text{T}_1({}^4\text{F})$ , or  ${}^4\text{T}_2({}^4\text{F})$ . These excited states undergo rapid non-radiative relaxation to the lowest excited state,  ${}^4\text{T}_2({}^4\text{F})$ . Radiative decay from this state to the  ${}^4\text{A}_2$  ground



**Fig. 3** (a) Diffuse reflectance spectra of GAGBO, GAGBO:0.08Cr<sup>3+</sup>, and GAGBO:0.15Cr<sup>3+</sup>,0.12Yb<sup>3+</sup>. (b) PLE and PL spectra of GAGBO:0.08Cr<sup>3+</sup>. (c) PL spectra of GAGBO:xCr<sup>3+</sup> (x = 0.03–0.15) upon 425 nm blue light excitation. (d) Temperature-dependent normalized integrated PL intensities of GAGBO:0.08Cr<sup>3+</sup>; the inset photo shows the luminescence temperature quenching schematic of Cr<sup>3+</sup> ions in GAGBO:0.08Cr<sup>3+</sup>. (e) Fitting line of  $\ln[(I_0/I_t) - 1]$  vs.  $[1/(kT)](eV^{-1})$ . (f) Comparison of thermal stability and external quantum efficiency between Cr<sup>3+</sup>-doped phosphors and GAGBO:0.08Cr<sup>3+</sup>.

state generates the observed NIR emission.<sup>28</sup> At elevated temperatures, however, electrons in the <sup>4</sup>T<sub>2</sub> (<sup>4</sup>F) state gain sufficient thermal energy to reach the crossing point between the excited-state and ground-state potential energy surfaces. This enables non-radiative deactivation to the ground state.<sup>29</sup> The energy barrier ( $\Delta E$ ) for this crossover fundamentally governs thermal stability: a larger  $\Delta E$  impedes thermal population of the crossing point, thereby favoring radiative emission and enhancing thermal stability.<sup>30,31</sup>

To quantitatively evaluate this effect, we calculated the activation energy  $\Delta E$  using the Arrhenius equation:<sup>32–34</sup>

$$I(T) = \frac{I_0}{1 + A_{\text{exp}}(-\Delta E/kT)} \quad (3)$$

As shown in Fig. 3e, the fitted  $\Delta E$  value for GAGBO:0.08Cr<sup>3+</sup> is calculated to be 0.256 eV. This high activation energy directly correlates with the observed superior thermal stability (93%@423 K) and the measured external quantum efficiency of 24%. As demonstrated in Fig. 3f, this performance surpasses the reported Cr<sup>3+</sup>-doped phosphors.

### 3.3. Energy transfer of Cr<sup>3+</sup>–RE<sup>3+</sup> co-doping

To investigate energy transfer (ET) from Cr<sup>3+</sup> to Ln<sup>3+</sup> (Ln<sup>3+</sup> = Yb, Nd and Er) in the GAGBO host, the PLE spectra were monitored at the characteristic emission wavelengths of Ln<sup>3+</sup>: 983 nm for Yb<sup>3+</sup>, 1063 nm for Nd<sup>3+</sup>, and 766 nm for Er<sup>3+</sup> (Fig. 4a, c and Fig. S5). These PLE spectra showed two broad excitation bands attributed to the spin-allowed <sup>4</sup>A<sub>2</sub> → <sup>4</sup>T<sub>1</sub>(<sup>4</sup>P)

and <sup>4</sup>A<sub>2</sub> → <sup>4</sup>T<sub>2</sub>(<sup>4</sup>F) transitions of Cr<sup>3+</sup>. When monitoring the Ln<sup>3+</sup> emission, these Cr<sup>3+</sup> excitation bands confirm the occurrence of energy transfer from Cr<sup>3+</sup> to Ln<sup>3+</sup>. Concentration-dependent PL spectra reveal that the PL intensity of Ln<sup>3+</sup> reaches a maximum at y = 0.12 for Yb<sup>3+</sup> (Fig. 4b), 0.08 for Nd<sup>3+</sup> (Fig. 4e) and 0.005 for Er<sup>3+</sup> (Fig. S5). Notably, beyond these critical values, the PL intensity of Ln<sup>3+</sup> decreases with further increase in the Ln<sup>3+</sup> doping concentration due to concentration quenching. Upon excitation at 425 nm, the decay lifetimes of Cr<sup>3+</sup> decrease with increasing Ln<sup>3+</sup> concentration (Fig. S6). The reduction in Cr<sup>3+</sup> decay lifetimes, as shown in Fig. 4c, d and Fig. S6, provides direct evidence for efficient ET from Cr<sup>3+</sup> to Ln<sup>3+</sup>. Collectively, the observation of Cr<sup>3+</sup> excitation bands in the Ln<sup>3+</sup>-monitored PLE spectra, the concentration dependence of Ln<sup>3+</sup> PL intensity, and the corresponding decrease in the Cr<sup>3+</sup> decay lifetime provide direct evidence for efficient energy transfer from Cr<sup>3+</sup> to Ln<sup>3+</sup> ions.

To quantify the  $\eta_{\text{ETE}}$  of Cr<sup>3+</sup>–Ln<sup>3+</sup>, decay curves of Cr<sup>3+</sup> emission were measured in GAGBO as a function of Ln<sup>3+</sup> doping concentration. The average lifetimes ( $\tau_{\text{ave}}$ ) were calculated using the following formula, with the results presented in Fig. 4c and f:<sup>35,36</sup>

$$\tau_{\text{ave}} = \frac{\int_0^{\infty} tI(t)dt}{\int_0^{\infty} I(t)dt} \quad (4)$$

These decay dynamics further confirm the occurrence and efficiency of the energy transfer processes.<sup>34</sup> The results reveal a significant decrease in the average decay lifetime of Cr<sup>3+</sup> ions



**Fig. 4** The (a) excitation spectra and (b) emission spectra of GAGBO:0.15Cr<sup>3+</sup>,yYb<sup>3+</sup> ( $y = 0.01$ – $0.12$ ). (c) Decay lifetimes and energy transfer efficiency ( $\eta_{ETE}$ ) dependent on the Yb<sup>3+</sup> doping concentration. The (d) excitation spectra and (e) emission spectra of GAGBO:0.15Cr<sup>3+</sup>,yNd<sup>3+</sup> ( $y = 0.03$ – $0.15$ ). (f) Decay lifetimes and  $\eta_{ETE}$  dependent on the Nd<sup>3+</sup> doping concentration. The normalized integrated emission intensity diagram of (g) GAGBO:0.15Cr<sup>3+</sup>,0.12Yb<sup>3+</sup> and (h) GAGBO:0.15Cr<sup>3+</sup>,0.08Nd<sup>3+</sup>. (i) PLQY measurement of GAGBO:0.15Cr<sup>3+</sup>,0.12Yb<sup>3+</sup> and GAGBO:0.15Cr<sup>3+</sup>,0.08Nd<sup>3+</sup>.

with increasing Ln<sup>3+</sup> concentration. For Yb<sup>3+</sup> co-doping,  $\tau_{ave}$  decreased from 6.42 ms to 2.25 ms. Similarly, for Nd<sup>3+</sup> co-doping,  $\tau_{ave}$  decreased from 4.08 ms to 1.04 ms. A parallel trend was observed in the Cr<sup>3+</sup>–Er<sup>3+</sup> co-doped system (Fig. S6). The  $\eta_{ETE}$  from Cr<sup>3+</sup> (sensitizer) to Yb<sup>3+</sup> or Nd<sup>3+</sup> (activator) can be estimated using the following equation:<sup>37,38</sup>

$$\eta_{ETE} \approx 1 - \frac{\tau_s}{\tau_{s0}} \quad (5)$$

where  $\tau_s$  and  $\tau_{s0}$  represent the decay lifetimes of Cr<sup>3+</sup> in the presence and absence of the acceptor ion (Ln<sup>3+</sup>). Fig. 4c and f show that the  $\eta_{ETE}$  increases with rising Ln<sup>3+</sup> content, indicating enhanced energy transfer. Notably, the maximum  $\eta_{ETE}$

values were 61%, 82% and 46% for the Cr<sup>3+</sup> → Yb<sup>3+</sup>, Nd<sup>3+</sup> and Er<sup>3+</sup> (Fig. S7) pairs, respectively.

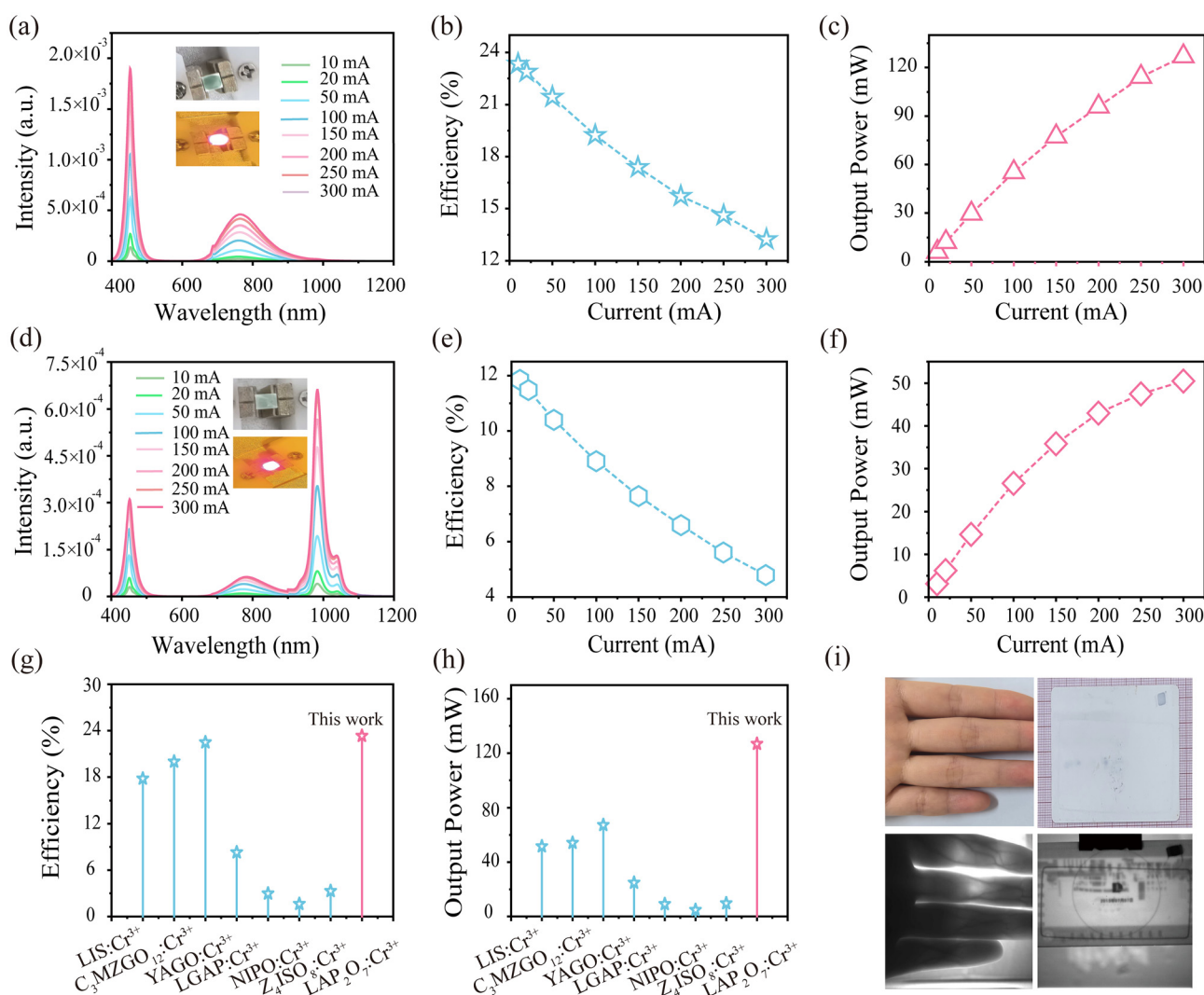
Long-term operation of pc-LEDs can elevate the temperature of the LED chip to 423 K or higher. Consequently, the working temperature of the LED chip is a critical factor influencing phosphor utilization efficiency. Temperature-dependent PL spectra of Cr<sup>3+</sup>–Ln<sup>3+</sup> co-doped samples were measured across a temperature gradient (303–573 K) to evaluate thermal stability. As shown in Fig. 4g, h and Fig. S8, the normalized integral emission intensity of all samples gradually decreases with increasing temperature. Notably, the Cr<sup>3+</sup>-doped sample exhibits significantly more pronounced thermal quenching. This substantial intensity reduction is attributed to thermally activated non-radiative relaxation pathways dominating at higher temperatures.<sup>39</sup>

In contrast, co-doping with  $\text{Yb}^{3+}$ ,  $\text{Nd}^{3+}$  or  $\text{Er}^{3+}$  ions substantially improves thermal stability. This enhancement stems from two key factors:<sup>40</sup> firstly, the energy transfer efficiency from  $\text{Cr}^{3+}$  to  $\text{Ln}^{3+}$  increases at elevated temperatures, allowing  $\text{Cr}^{3+}$  to transfer a larger fraction of its absorbed energy before the occurrence of non-radiative losses, thereby mitigating thermal quenching within the  $\text{Cr}^{3+}$  system itself;<sup>41–43</sup> secondly, the characteristic NIR emissions of  $\text{Ln}^{3+}$  demonstrate excellent intrinsic thermal stability. Quantitatively, 94% and 100% of the normalized emission intensities are retained at 423 K for the  $\text{Yb}^{3+}$  and  $\text{Nd}^{3+}$  co-doped samples, respectively. This synergistic effect leads to superior overall thermal performance for the co-doped phosphors. A similar improvement in thermal stability is observed upon introducing  $\text{Er}^{3+}$  ions, as detailed in Fig. S9. Furthermore,  $\text{Cr}^{3+}$ - $\text{Ln}^{3+}$  co-doping yielded internal

quantum efficiency (IQE) values of 86% for  $\text{Cr}^{3+}$ - $\text{Yb}^{3+}$ , 38% for  $\text{Cr}^{3+}$ - $\text{Nd}^{3+}$ , and 24% for  $\text{Cr}^{3+}$ - $\text{Er}^{3+}$ , respectively. The combination of exceptionally high IQE and excellent thermal stabilities for the  $\text{Cr}^{3+}$ - $\text{Ln}^{3+}$  co-doped phosphors highlights their potential as promising candidate phosphors for high-performance NIR pc-LEDs.

### 3.4. Luminescence performance and applications

To evaluate the practical application potential of  $\text{GAGBO}:\text{Cr}^{3+}$  and  $\text{GAGBO}:\text{Cr}^{3+}$ - $\text{Ln}^{3+}$  phosphors, NIR pc-LEDs were fabricated by coating these four types of phosphors onto 450 nm blue light chips. When the driving current increases from 10 mA to 300 mA, the electroluminescence (EL) intensity gradually increases, as shown in Fig. 5a and d. From Fig. 5b, c, e and f, the output power of the NIR pc-LED chip increases



**Fig. 5** The (a) emission spectra, (b) photoelectric conversion efficiency (PCE) and (c) output power of  $\text{GAGBO}:\text{Cr}^{3+}$  phosphor-based NIR pc-LEDs; the inset shows a photograph of the LED device. The (d) emission spectra, (e) PCE and (f) output power of  $\text{GAGBO}:\text{Cr}^{3+}$ ,  $\text{Yb}^{3+}$  phosphor-based NIR pc-LEDs; the inset shows a photograph of the LED device. Comparison of (g) PCE at 10 mA and (h) output power at 300 mA for the  $\text{Cr}^{3+}$  phosphor-based NIR pc-LEDs. (i) NIR images of a female palm's veins and a campus ID card, illuminated by visible light and custom-built pc-LEDs.

with the current, while the photonic conversion efficiency gradually decreases. At a driving current of 300 mA, the output powers of the GAGBO:Cr<sup>3+</sup> and GAGBO:Cr<sup>3+</sup>-Ln<sup>3+</sup> pc-LED chips reach 127 mW, 51 mW, 10 mW, and 12 mW. The photonic conversion efficiencies of the GAGBO:Cr<sup>3+</sup> and GAGBO:Cr<sup>3+</sup>,Yb<sup>3+</sup> pc-LED chips are 13% and 4.8%, respectively. Compared to the PCE at 10 mA and output power of NIR pc-LEDs at 300 mA reported previously (Tables S1 and S4), GAGBO:Cr<sup>3+</sup> and GAGBO:Cr<sup>3+</sup>,Yb<sup>3+</sup> pc-LEDs exhibit superior performance (Fig. 5g and h), demonstrating their versatile potential.

Considering the excellent luminescence properties of these phosphors, the practical applications of GAGBO:Cr<sup>3+</sup>, GAGBO:Cr<sup>3+</sup>-Ln<sup>3+</sup> were investigated. The 10 W high-power LED chips fabricated with the NIR phosphor samples prepared in this study highlight their significant potential for non-destructive testing and human vein imaging and recognition. The fabricated LED chips served as NIR light sources to capture images of a plastic campus card and a human hand under complete darkness. The captured scenes and effects are shown in Fig. 5i. When photographed with a regular digital camera under visible light, the external features of the object were visible. However, nothing was visible when the visible light source was turned off and the photo was taken using the same digital camera. In contrast, when only the NIR light source was activated and photographed with an NIR camera, a clear image of the card (including the integrated circuit structure) and the veins and bones of the hand could be observed. The NIR light source demonstrates excellent night vision capabilities, non-destructive testing abilities, and effective tissue penetration for human body imaging.

## 4. Conclusion

This work demonstrates a subgrid-cage confinement strategy to overcome the fundamental challenge of uncontrollable energy migration in Cr<sup>3+</sup>-Ln<sup>3+</sup> phosphors. The discrete bilayer cage structure within GdAl<sub>1.5</sub>Ga<sub>1.5</sub>(BO<sub>3</sub>)<sub>4</sub> enables precise localization of Cr<sup>3+</sup> (octahedral sites) and Ln<sup>3+</sup> (dodecahedral sites), constraining their separation to the optimal 3.673 Å. This architecture achieves ultra-broadband NIR emission (650–1600 nm), fully spanning all biological transparency windows, through highly efficient Cr<sup>3+</sup> → Ln<sup>3+</sup> energy transfer ( $\eta_{\text{ETE}}$ : 61% for Yb<sup>3+</sup>, 82% for Nd<sup>3+</sup>, and 46% for Er<sup>3+</sup>). Crucially, the strategy simultaneously suppresses detrimental Ln<sup>3+</sup> migration and maximizes sensitizer-activator interaction, yielding record performance: a PLQY of 86% for Cr<sup>3+</sup>-Yb<sup>3+</sup> and exceptional thermal stability (94%@423 K). The fabricated NIR pc-LEDs deliver industry-leading output power (127 mW) and photoelectric efficiency (13%) under a 300 mA driving current, enabling high-contrast biological imaging applications. This subgrid-cage confinement paradigm provides a universal solution for overcoming the quantum efficiency bottleneck in next-generation broadband NIR phosphors.

## Author contributions

Yang Li conceived the idea, designed the experiment, and analyzed the data. Simeng Cao provided samples for all measurements and collected all data. Ximei An, Lei Yang, Mengting Gao, Zhiyue Yang, Chao He and Zonglong Guo carried out device-fabricated characterization. Yang Li, Shaoan Zhang and Simeng Cao contributed to the technical discussions of results. Simeng Cao wrote the manuscript. Shaoan Zhang and Yang Li improved the manuscript and directed and supervised the project. All authors discussed and commented on the manuscript.

## Conflicts of interest

There are no conflicts to declare.

## Data availability

The authors confirm that the data supporting the findings of this study are available within the article. Supplementary information is available. See DOI: <https://doi.org/10.1039/d5qi01468a>.

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